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# MOS INTEGRATED CIRCUIT $\mu PD5205$

# C-MOS ANALOG MULTIPLEXER

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#### DESCRIPTION

The  $\mu$ PD5205 is 8-channel C-MOS analog multiplexer. A single-pole 8-position mode and double-pole 4-position mode are settable by 8/4 terminal. TTL/C-MOS compatible input threshold (EN,  $\overline{CS}$ ,  $\overline{WR}$ , RS) make the circuit directly driven by microprocessor. Further advantage each switch has low ON resistance, low leak current and wide analog input range. By these features, the  $\mu$ PD5205 is the optimum choice for data acquisition system.

#### TYPICAL CHARACTERISTICS

- Wide Supply Voltage: 44 V
- Low ON Resistance: 270  $\Omega$  TYP. (T<sub>a</sub> = 25 °C)
- Low Source OFF Leak Current: 5 nA MAX. ( $T_a = 25^{\circ}$ C)
- Low Drain ON/OFF Leak Current: 20 nA MAX. (Ta = 25 °C)
- Guaranteed Break-Before-Make Operation

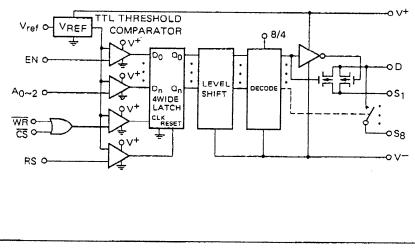
#### **FEATURES**

- A single-pole 8 position mode and double-pole 4 position mode are settable.
- TTL/C-MOS compatible digital input level. (EN, CS, WR, RS)
- Analog input voltage range includes V<sup>+</sup> and V<sup>-</sup>.

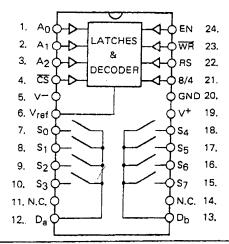
#### ORDERING INFORMATION

| Part Number | Package                            |
|-------------|------------------------------------|
| μPD5205CA   | 24PIN PLASTIC SHRINK DIP (300 mil) |
| μPD5205G    | 24PIN PLASTIC SOP (300 mil)        |

#### EQUIVALENT CIRCUIT



#### **CONNECTION DIAGRAM (Top View)**



NEC cannot assume any responsibility for any circuits shown or represent that they are free from patent infringement.

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# ABSOLUTE MAXIMUM RATINGS (T<sub>a</sub>=25 °C)

| Supply Voltage between V <sup>+</sup> and V <sup>-</sup>                        | V <sup>+</sup> V <sup>-</sup> | 44          | V  |
|---|-------------------------------|-------------|----|
| Supply Voltage between $V^+$ and GND  | V <sup>+</sup> -GND           | 25          | V  |
| Supply Voltage between GND and V <sup>-</sup>                                   | GND-V-                        | 25          | V  |
| Input Current (Digital Input and S, D)  |                               | 30          | mA |
| Continuous Current between Source and Drain                                     |                               | 20          | mĂ |
| Peak Current between Source and Drain<br>(Pulsed at 1 ms, 10 % Duty Cycle Max.) |                               | 40          | mΑ |
| Power Dissipation   | Pt                            | 570         | mW |
| Operating Temperature   | T <sub>opt</sub>              | -20 to +85  | °C |
| Storage Temperature   | T <sub>stg</sub>              | -55 to +125 | °C |

# RECOMMENDED OPERATING CONDITIONS (T\_a=25 $^\circ\text{C})$

| CHARACTERISTICS   | SYMBOL          | MIN. | TYP. | MAX. | UNIT |
|---|-----------------|------|------|------|------|
| Supply Voltage  | V±              | ±8   | ±15  | ±16  | v    |
| Low Level Logic Input Voltage (at V*=±15 V)               | VINL            |      |      | 0.8  | v    |
| High Level Logic Input Voltage (at V <sup>±</sup> =±15 V) | VINH            | 2.4  |      |      | v    |
| Minimum Write Pulse Width (Ta=Topt)                       | tww             | 300  |      |      | ns   |
| Data Settling Time (T <sub>a</sub> =T <sub>opt</sub> )    | <sup>t</sup> DW | 100  |      |      | лs   |
| Data Hold Time (T <sub>a</sub> =T <sub>opt</sub> )        | twD             | 180  |      |      | ns   |
| Minimum Reset Pulse Width (Ta=Topt)                       | tRS             | 500  |      |      | ns   |

# ELECTRICAL CHARACTERISTICS (V<sup>±</sup>=±15 V, GND=0)

|   | 0.000                   | TYP.            |            | MAX.       | - <u>-</u>        | 1    |  |  |
|---|-------------------------|-----------------|------------|------------|-------------------|------|--|--|
| CHARACTERISTIC  | SYMBOL                  | 25 °C           | -20 °C     | 25 °C      | 85 °C             |      | TEST CON   | DITIONS  |
| Analog Input Voltage  | VANALOG                 | ±15             |            | ±15        | ±15               | v    |  |  |
| Drain-Source<br>ON Resistance                                   | R <sub>DS(ON)</sub>     | 270<br>230      | 450<br>450 | 450<br>450 | 550<br>550        | Ω    | V <sub>D</sub> =10 V<br>V <sub>D</sub> =10 V                             | VINL=0.8 V<br>VINH=2.4 V<br>I <sub>S</sub> =200 µA |
| Drain-Source<br>ON Resistance<br>Matching<br>(Between Channels) | ∆R <sub>DS</sub> (ON)   | 6               |            |            |                   | %    | $\frac{R_{DS(ON)} MAX}{R_{DS(ON)}}$                                      | -RDS(ON) MIN.                                      |
| Source OFF  |                         | -0.005          |            | ±5         | ±50               |      | V <sub>s</sub> ≖10 V<br>V <sub>D</sub> ≖−10 V                            |  |
| Leakage<br>Current  | IS(OFF)                 | -0.005          |            | ±5         | ±50               |      | V <sub>s</sub> =-10 V<br>V <sub>D</sub> =10 V                            |  |
| Drain OFF   |                         | -0.008          |            | ±20        | +100              | nA   | V <sub>D</sub> =10 V<br>V <sub>s</sub> =-10 V                            | V <sub>EN</sub> =0                                 |
| Leakage<br>Current  | <sup>I</sup> D(OFF)     | -0.008          |            | ±20        | +100              |      | V <sub>D</sub> =−10 V<br>V <sub>s</sub> =10 V                            |  |
| Drain ON<br>Leakage   | ID(ON)                  | 0.015           |            | ±20        | +100              | nA   | V <sub>D</sub> =V <sub>s(all)</sub> =10 V                                |  |
| Current   |                         | 0.015           |            | ±20        | +100              |      | VD=Vs(all)=-10   | V VINH=2.4 V                                       |
| High Level<br>Logic Input                                       | <sup>†</sup> імн        | -0.002<br>0.006 |            | 10         | -30<br>30         |      | V <sub>IN</sub> =2.4 V<br>V <sub>IN</sub> =15 V                          |  |
| Current<br>Low Level<br>Logic Input<br>Current                  | INL                     | -0.002          |            | -10        | -30               | - μΑ | VIN=0 V  |  |
| Switching<br>Time of<br>Multiplexer                             | <sup>t</sup> transition | 0.6             |            | 1          |                   | μs   |  |  |
| Break Before<br>Make Interval                                   | <sup>t</sup> open       | 0.2             |            | 0.5        | · · · · · · · · · | μs   |  |  |
| Turn ON Time<br>(EN, WR, CS)                                    | ton                     | 0.5             |            | 1          |                   | μs   |  |  |
| Turn OFF Time<br>(EN, RS, CS)                                   | tOFF                    | 0.5             |            | 1          |                   | μs   |  |  |
| Charge Injection  | ٩                       | 20              |            |            |                   | рС   |  |  |
| OFF Isolation   | OIRR                    | 68              |            |            |                   | dB   | VEN=0, RL=1 K,<br>Vs=7 Vr.m.s., f=50                                     | -  |
| Logic Input<br>Capacitance                                      | C <sub>in</sub>         | 2.5             |            |            |                   | pF   |  |  |
| Source OFF<br>Capacitance                                       | CS(OFF)                 | 5               |            |            |                   | -5   | VS=0. VEN=0, WF<br>CS=0, f=140 kHz                                       | ₹=0,   |
| Drain OFF<br>Capacitance  | C <sub>D(OFF)</sub>     | 12              |            |            |                   | pF   | V <sub>D</sub> =0, V <sub>EN</sub> =0, W<br>C <sub>S</sub> =0, f=140 kHz | R=0,   |

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|                            |        | TYP. | MAX.  |       |       | UNIT | TEST CONDITIONS                        |  |  |
|----------------------------|--------|------|-------|-------|-------|------|--|--|--|
| CHARACTERISTIC             | SYMBOL | 25°C | -20°C | 25 °C | 85 °C |      |  |  |  |
| Positive<br>Supply Current | 1+     |      |       | 2.5   |       | - mA | VEN=0, VAX=0                           |  |  |
| Negative<br>Supply Current | 1-     |      |       | -1.5  |       |      | V <sub>EN</sub> =0. V <sub>AX</sub> ≠0 |  |  |

#### Notes:

Please connect V<sup>-</sup>pin to the minimum voltage level and have a care that V<sup>-</sup>will not go to open or not go to higher than GND 1. pin.

Please connect N.C. pin (11, 14 pin) to GND in order to improve Off Isolation. 2.

μPD5205G has large chip size. Therefore we recommend hot plate belt conveyer type reflow soldering for mounting. 3. Wave soldering or infrared rays type reflow soldering methods are not recommendable because of their hard heat shock.

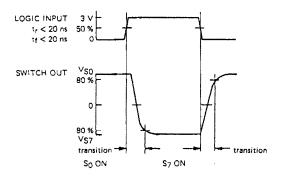
#### MEASUREMENT CIRCUIT

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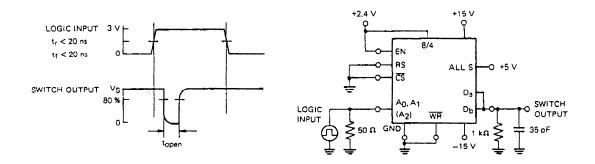
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#### Fig. 1 Switching Time of Multiplexer



Double-pole 4 position mode Single-pole 8 position mode +15 V +2.4 V +2.4 V +15 V Ŧ Ŷ Ŷ 0 8/4 8/4 S<sub>0</sub> -0 ± 10 V -O ± 10 V ΕN so ΕN --<u>o</u>-RS RŞ 0 C S1~S6 OTHERS ੀ <u>čs</u> ĈŜ 0 -0 ± 10 V S7 -0 ± 10 V Sз  $\sim$ Ao AO 0 0 Aı Da -O. SWITCH A1  $\mathbf{o}$ A2 Db Da WR WR A2 <u>}</u> ₹ 50 Ω GND] 35 pF LOGIC INPUT 1 M 35 pF ₹50 Ω þ P  $\odot$ δ T GNDO Ŷ –15 V –15 V

Fig. 2 Brake Before Make Interval

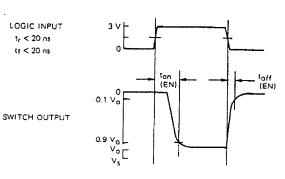


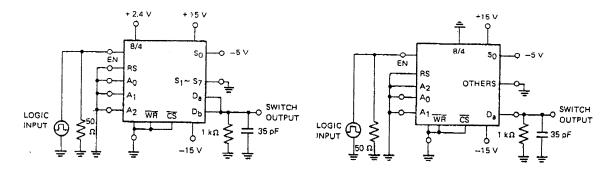
#### Fig. 3 Turn ON/OFF Time of EN

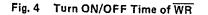
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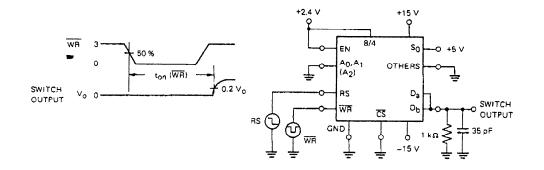
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LOGIC INPUT t<sub>r</sub> < 20 ns tf < 20 ns

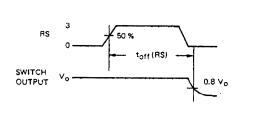


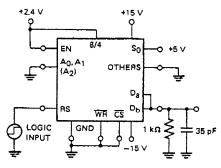




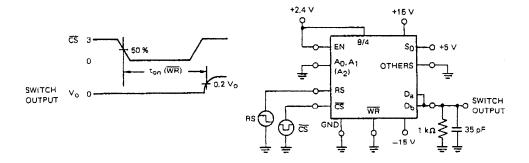




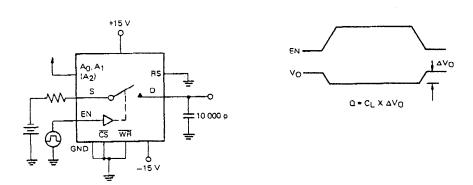




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Fig. 8 Data Settling/Hold Time

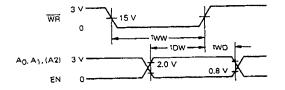
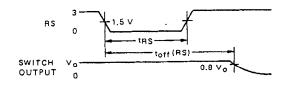


Fig. 9 Reset Pulse Width



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# FUNCTION

| PIN | SYMBOL           | FUNCTION                                    |
|-----|------------------|---|
| 1   | Ao               | SW Control Input                            |
| 2   | A <sub>1</sub>   | SW Control Input                            |
| 3   | A <sub>2</sub>   | SW Control Input                            |
| 4   | <u>cs</u>        | Chip Select. Active Low.                    |
| 5   | V-               | Negative supply Voltage (-15 V)             |
| 6   | V <sub>ref</sub> | Input threshold Level Control               |
| 7   | S <sub>0</sub>   | SW Input/Output                             |
| 8   | S <sub>1</sub>   | SW Input/Output                             |
| 9   | S <sub>2</sub>   | SW Input/Output                             |
| 10  | S3               | SW Input/Output                             |
| 11  | N. C.            | Non Connection (connect to GND)             |
| 12  | Da               | SW Input                                    |
| 13  | . Db             | SW Input                                    |
| 14  | N. C.            | Non Connection (connect to GND)             |
| 15  | \$7              | SW Input/Output                             |
| 16  | S <sub>6</sub>   | SW Input/Output                             |
| 17  | S <sub>5</sub>   | SW Input/Output                             |
| 18  | S4               | SW Input/Output                             |
| 19  | V+               | Positive Supply Voltage (+15 V)             |
| 20  | GND              | GND (0 V)                                   |
| 21  | 8/4              | Mode Control ("H": 8channel, "L": 4channel) |
| 22  | RS               | Reset                                       |
| 23  | WR               | Write Request. Active Low.                  |
| 24  | EN               | Enable                                      |

NAME OF BUILDING

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## TRUTH TABLE

|         | EN | 8/4 |    |    |    | A0 L | RS |    | CI | 1 <b>1</b> |        |         | CI  | n 2 |    |
|---------|----|-----|----|----|----|------|----|----|----|------------|--------|---------|-----|-----|----|
|         | EN | 0/4 | A2 | A1 | A0 |      | па | 0  | 1  | 2          | 3      | 4       | 5   | 6   | 7  |
|         | •  | •   | •  | •  | •  | 5    | 0  |    |    |            | La     | itch    |     |     | •  |
|         | •  | •   | •  | •  | •  | •    | 1  |    |    | Lat        | ch Cle | ar/SW ( | DFF |     |    |
|         | 0  | •   | •  | •  | •  | 0    | 0  | 1  |    |            | SW     | OFF     |     |     |    |
|         | 1  | 0   | *  | 0  | 0  | 0    | 0  | ON |    |            |        | ON      |     |     |    |
| 4<br>Ch | 1  | 0   | •  | 0  | 1  | 0    | 0  |    | ON |            |        |         | ON  |     |    |
| *       | 1  | 0   | •  | 1  | 0  | 0    | 0  |    |    | ON         |        |         |     | ON  |    |
| -       | 1  | 0   | *  | 1  | 1  | 0    | 0  |    |    |            | ON     |         |     |     | ON |
|         | 1  | 1   | 0  | 0  | 0  | 0    | 0  | ON |    |            |        |         |     |     |    |
|         | 1  | 1   | 0  | 0  | 1  | 0    | 0  |    | ON |            |        |         |     |     |    |
| 8       | 1  | 1   | 0  | 1  | 0  | 0    | 0  |    |    | ON         |        |         |     |     |    |
| Ch      | 1  | 1   | 0  | 1  | 1  | 0    | 0  |    |    |            | ON     |         |     |     |    |
| 1       | 1  | 1   | 1  | 0  | 0  | 0    | 0  |    |    |            |        | ON      |     |     |    |
|         | 1  | 1   | 1  | 0  | 1  | 0    | 0  |    |    |            |        |         | ON  |     |    |
|         | 1  | 1   | 1  | 1  | 0  | 0    | 0  |    |    |            |        |         |     | ON  |    |
|         | 1  | 1   | 1  | 1  | 1  | 0    | 0  |    |    |            |        |         |     |     | ON |

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\* Don't Care

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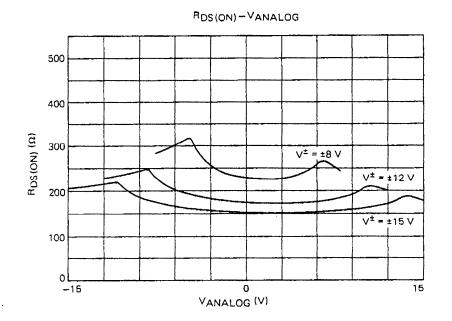


After reset, all switches remain off until chip select signal becomes active.

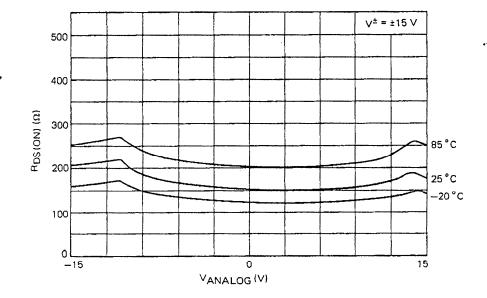
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# NEEC MARTIN STATES

## TYPICAL CHARACTERISTICS ( $T_a = 25$ °C)



RDS(ON)-VANALOG



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# AC CHARACTERISTICS

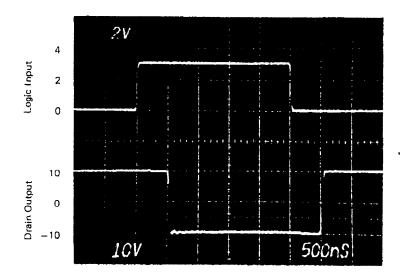


Photo. 1 Switching Time of Multiplexer ( $V_{ANALOG} = \pm 10 V$ )

Photo. 2 Brake Before Make Interval (VANALOG = 5 V)

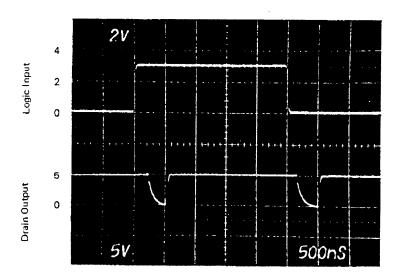


Photo. 3 Switch ON/OFF Time of EN  $\{V_{ANALOG} = -5 V\}$ 

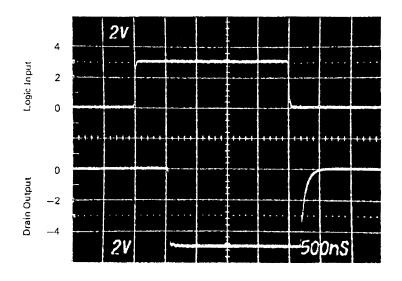
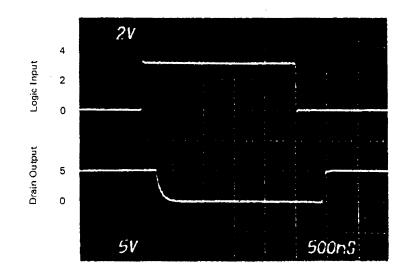


Photo. 4 Switch OFF Time of RS ( $V_{ANALOG} = 5 V$ )

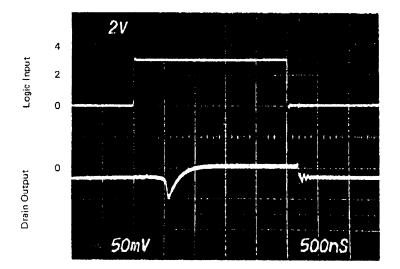


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Photo. 5 Charge Injection

STEC monormer

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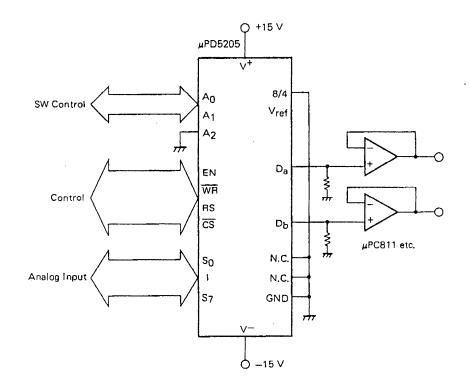


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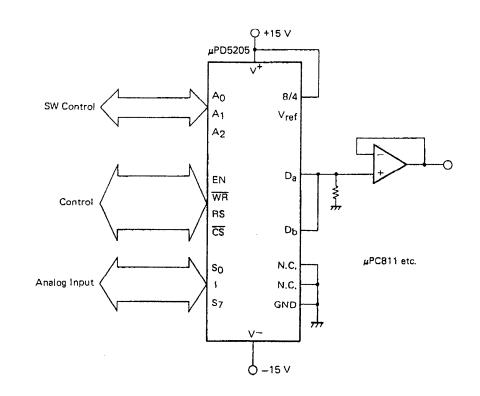
S. D. C. Manual and Start

#### APPLICATION CIRCUIT

#### (1) Double-pole 4position mode



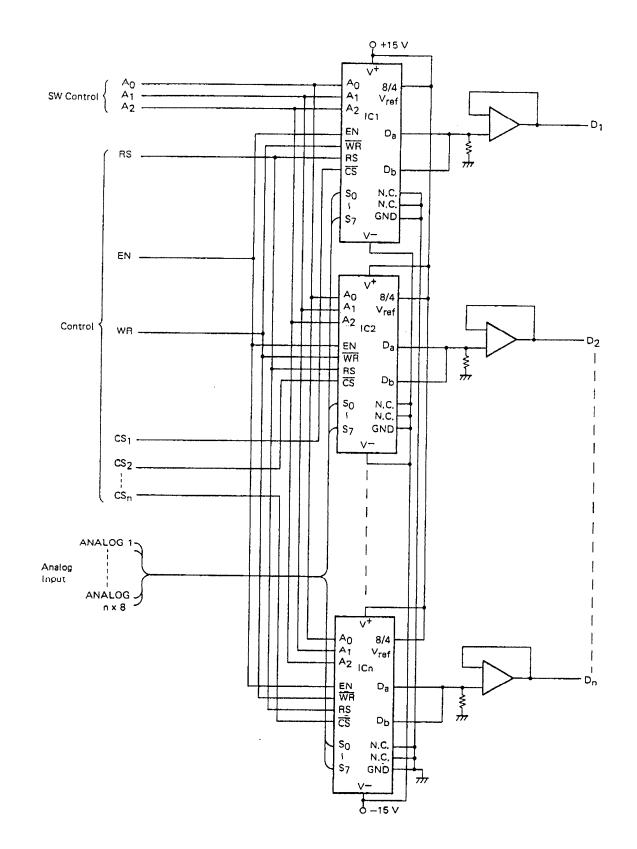
(2) Single-pole 8position mode



(3) Multi Connection

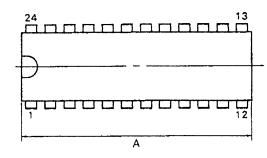
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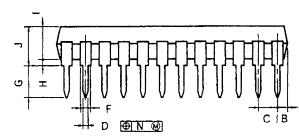
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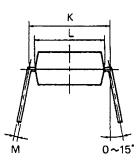


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#### 24PIN PLASTIC SHRINK DIP (300 mil)







\$24C-70-3008

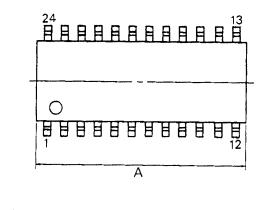
#### NOTES

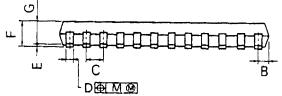
- Each lead centerline is located within 0.17 mm (0.007 inch) of its true position (T.P.) at maximum material condition.
- Item "K" to center of leads when formed parallel.

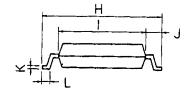
| ITEM | MILLIMETERS         | INCHES                  |
|------|---------------------|-------------------------|
| A    | 23.12 MAX.          | 0.911 MAX.              |
| В    | 1.78 MAX.           | 0.070 MAX.              |
| с    | 1.778 (T.P.)        | 0.070 (T.P.)            |
| D    | 0.50 ±0.10          | 0.020 - 8.005           |
| F    | 0.85 MIN.           | 0.033 MIN.              |
| G    | 3.2 <sup>±0.3</sup> | 0.126 <sup>±0.012</sup> |
| н    | 0.51 MIN.           | 0.020 MIN.              |
| 1    | 4.31 MAX.           | 0.170 MAX.              |
| J    | 5.08 MAX.           | 0.200 MAX.              |
| к    | 7.62 (T.P.)         | 0.300 (T.P.)            |
| L    | 6.5                 | 0.256                   |
| м    | 0.25-8:35           | 0.010-0.003             |
| N    | 0.17                | 0.007                   |

## 24PIN PLASTIC SOP (300 mil)

NE SCHAMMERINA







#### P24GM-50-300B

#### NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS         | INCHES                  |
|------|---------------------|-------------------------|
| A    | 15.54 MAX.          | 0.612 MAX.              |
| В    | 0.78 MAX.           | 0.031 MAX.              |
| С    | 1.27 (T.P.)         | 0.050 (T.P.)            |
| D    | 0.40 - 0.05         | 0.016-0.003             |
| E    | 0.1 <sup>±0.1</sup> | 0.004 <sup>±0.004</sup> |
| F    | 1.8 MAX.            | 0.071 MAX.              |
| G    | 1.55                | 0.061                   |
| н    | 7.7 <sup>±0.3</sup> | 0.303 ±0.012            |
| ł    | 5.6                 | 0.220                   |
| J    | 1.1                 | 0.043                   |
| к    | 0.20 - 0.19         | 0.008-0.004             |
| L    | 0.6 <sup>±0.2</sup> | 0.024 + 8:88            |
| М    | 0.12                | 0.005                   |

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IC-2186 February 1988P Printed in Japan